



FGH75N60SF

600V, 75A Field Stop IGBT

Features

- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 2.3V @ I_C = 75A$
- High Input Impedance
- Fast Switching
- RoHS Compliant

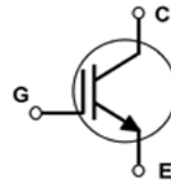
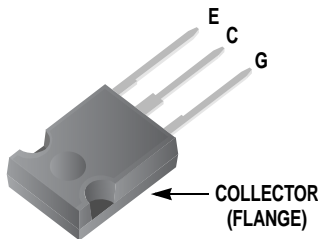
Applications

- Induction Heating, UPS, SMPS, PFC



General Description

Using Novel Field Stop IGBT Technology, Fairchild's new series of Field Stop IGBTs offer the optimum performance for Induction Heating, UPS, SMPS and PFC applications where low conduction and switching losses are essential.



Absolute Maximum Ratings

| Symbol | Description | Ratings | Units |
|--------------|---|-------------|------------|
| V_{CES} | Collector to Emitter Voltage | 600 | V |
| V_{GES} | Gate to Emitter Voltage | ± 20 | V |
| I_C | Collector Current @ $T_C = 25^\circ C$ | 150 | A |
| | Collector Current @ $T_C = 100^\circ C$ | 75 | A |
| $I_{CM} (1)$ | Pulsed Collector Current @ $T_C = 25^\circ C$ | 225 | A |
| P_D | Maximum Power Dissipation @ $T_C = 25^\circ C$ | 452 | W |
| | Maximum Power Dissipation @ $T_C = 100^\circ C$ | 181 | W |
| T_J | Operating Junction Temperature | -55 to +150 | $^\circ C$ |
| T_{stg} | Storage Temperature Range | -55 to +150 | $^\circ C$ |
| T_L | Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds | 300 | $^\circ C$ |

Notes:
1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

| Symbol | Parameter | Typ. | Max. | Units |
|-----------------------|---|------|-------|--------------|
| $R_{\theta JC}(IGBT)$ | Thermal Resistance, Junction to Case | - | 0.276 | $^\circ C/W$ |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | - | 40 | $^\circ C/W$ |

Package Marking and Ordering Information

| Device Marking | Device | Package | Packaging Type | Qty per Tube | Max Qty per Box |
|----------------|--------------|---------|----------------|--------------|-----------------|
| FGH75N60SF | FGH75N60SFTU | TO-247 | Tube | 30ea | - |

Electrical Characteristics of the IGBT T_C = 25°C unless otherwise noted

| Symbol | Parameter | Test Conditions | Min. | Typ. | Max. | Units |
|--------------------------------------|--|--|------|------|------|-------|
| Off Characteristics | | | | | | |
| BV _{CES} | Collector to Emitter Breakdown Voltage | V _{GE} = 0V, I _C = 250μA | 600 | - | - | V |
| $\frac{\Delta BV_{CES}}{\Delta T_J}$ | Temperature Coefficient of Breakdown Voltage | V _{GE} = 0V, I _C = 250μA | - | 0.4 | - | V/°C |
| I _{CES} | Collector Cut-Off Current | V _{CE} = V _{CES} , V _{GE} = 0V | - | - | 250 | μA |
| I _{GES} | G-E Leakage Current | V _{GE} = V _{GES} , V _{CE} = 0V | - | - | ±400 | nA |
| On Characteristics | | | | | | |
| V _{GE(th)} | G-E Threshold Voltage | I _C = 250μA, V _{CE} = V _{GE} | 4.0 | 5.0 | 6.5 | V |
| V _{CE(sat)} | Collector to Emitter Saturation Voltage | I _C = 75A, V _{GE} = 15V | - | 2.3 | 2.9 | V |
| | | I _C = 75A, V _{GE} = 15V, T _C = 125°C | - | 2.6 | - | V |
| Dynamic Characteristics | | | | | | |
| C _{ies} | Input Capacitance | V _{CE} = 30V, V _{GE} = 0V, f = 1MHz | - | 3850 | - | pF |
| C _{oes} | Output Capacitance | | - | 375 | - | pF |
| C _{res} | Reverse Transfer Capacitance | | - | 147 | - | pF |
| Switching Characteristics | | | | | | |
| t _{d(on)} | Turn-On Delay Time | V _{CC} = 400V, I _C = 75A, R _G = 3Ω, V _{GE} = 15V, Inductive Load, T _C = 25°C | - | 26 | - | ns |
| t _r | Rise Time | | - | 58 | - | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 138 | - | ns |
| t _f | Fall Time | | - | 22 | 60 | ns |
| E _{on} | Turn-On Switching Loss | | - | 2.7 | - | mJ |
| E _{off} | Turn-Off Switching Loss | | - | 1.0 | - | mJ |
| E _{ts} | Total Switching Loss | - | 3.7 | - | mJ | |
| t _{d(on)} | Turn-On Delay Time | V _{CC} = 400V, I _C = 75A, R _G = 3Ω, V _{GE} = 15V, Inductive Load, T _C = 125°C | - | 25 | - | ns |
| t _r | Rise Time | | - | 62 | - | ns |
| t _{d(off)} | Turn-Off Delay Time | | - | 138 | - | ns |
| t _f | Fall Time | | - | 21 | - | ns |
| E _{on} | Turn-On Switching Loss | | - | 3.2 | - | mJ |
| E _{off} | Turn-Off Switching Loss | | - | 1.3 | - | mJ |
| E _{ts} | Total Switching Loss | - | 4.5 | - | mJ | |
| Q _g | Total Gate Charge | V _{CE} = 400V, I _C = 75A, V _{GE} = 15V | - | 250 | - | nC |
| Q _{ge} | Gate to Emitter Charge | | - | 30 | - | nC |
| Q _{gc} | Gate to Collector Charge | | - | 130 | - | nC |

Typical Performance Characteristics

Figure 1. Typical Output Characteristics

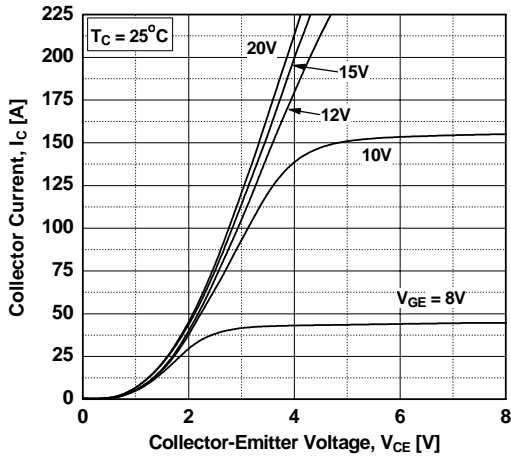


Figure 2. Typical Output Characteristics

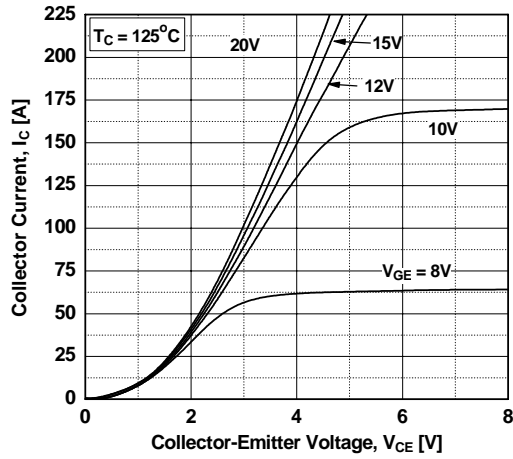


Figure 3. Typical Saturation Voltage Characteristics

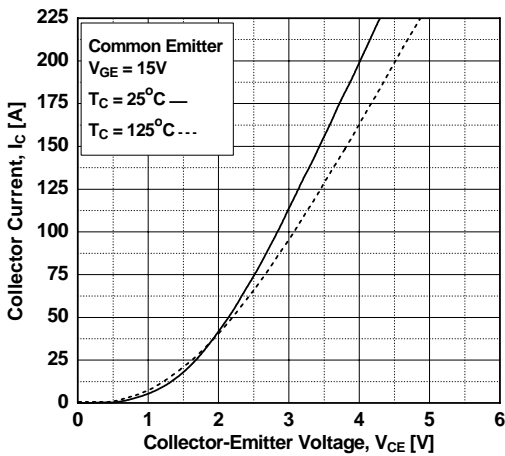


Figure 4. Transfer Characteristics

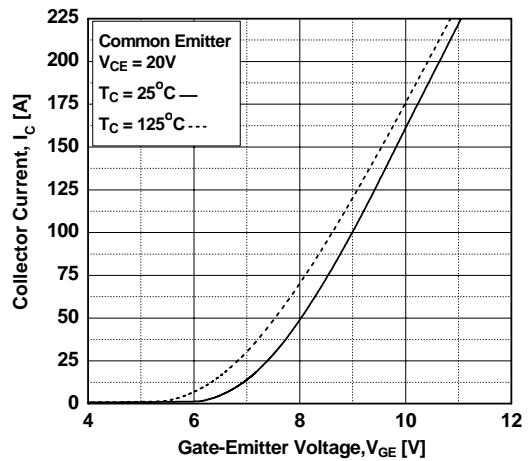


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

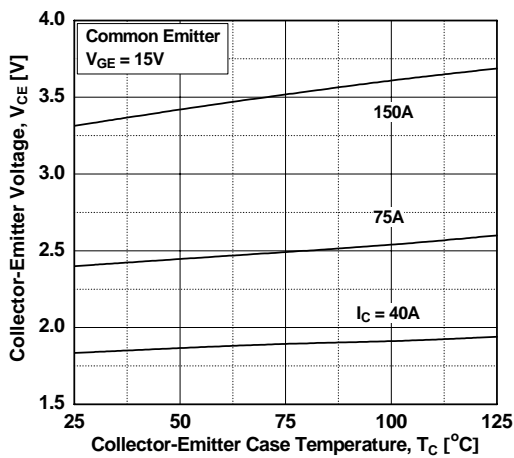
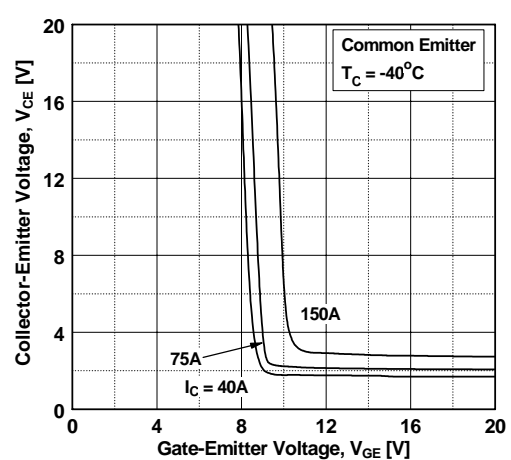


Figure 6. Saturation Voltage vs. Vge



Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

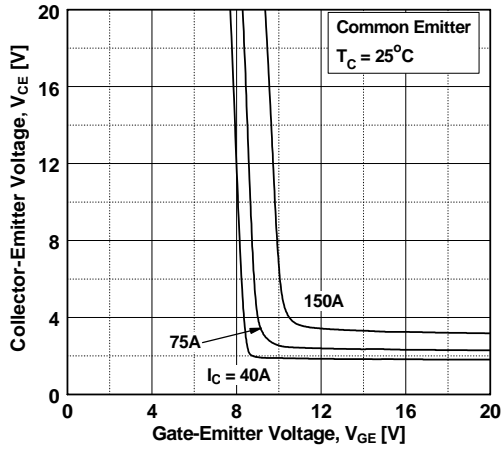


Figure 8. Saturation Voltage vs. V_{GE}

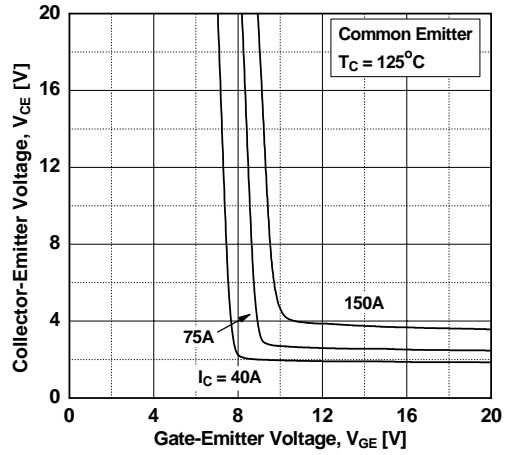


Figure 9. Capacitance Characteristics

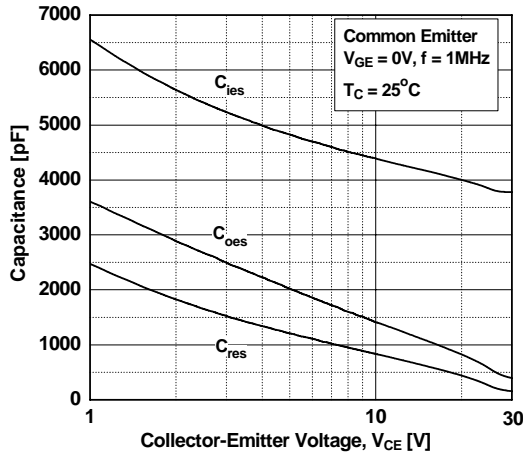


Figure 10. Gate charge Characteristics

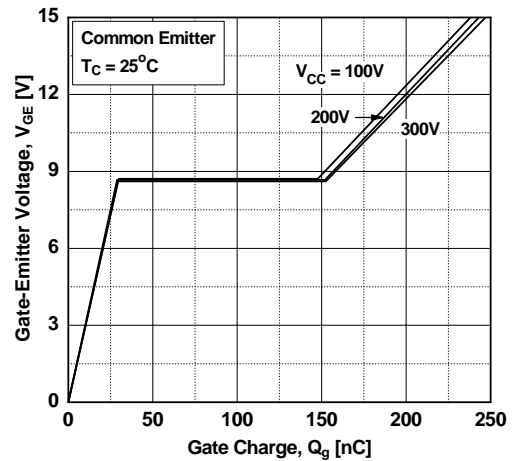


Figure 11. SOA Characteristics

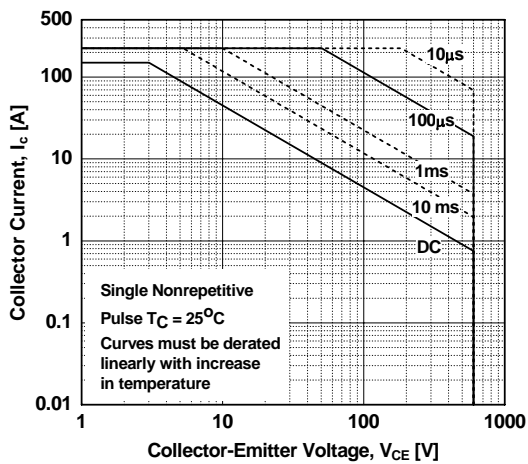
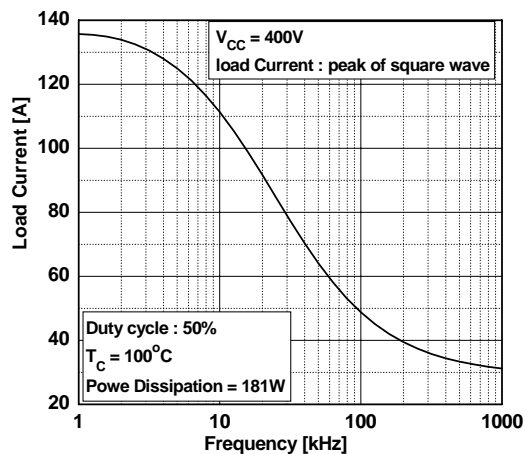


Figure 12. Load Current vs. Frequency



Typical Performance Characteristics

Figure 13. Turn-on Characteristics vs. Gate Resistance

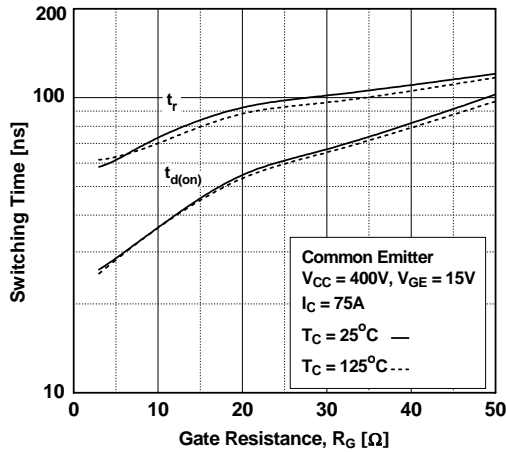


Figure 14. Turn-off Characteristics vs. Gate Resistance

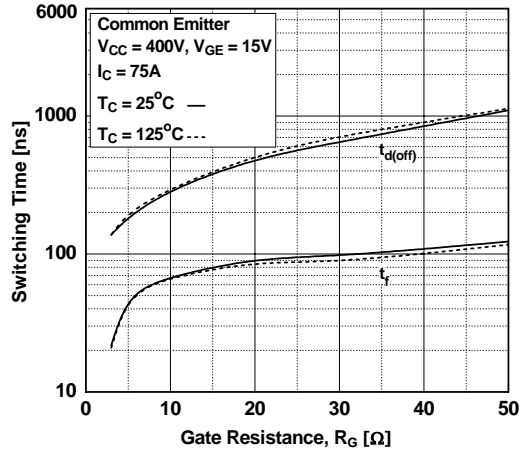


Figure 15. Turn-on Characteristics vs. Collector Current

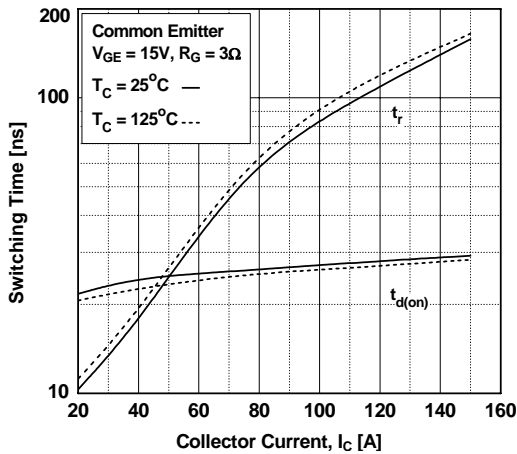


Figure 16. Turn-off Characteristics vs. Collector Current

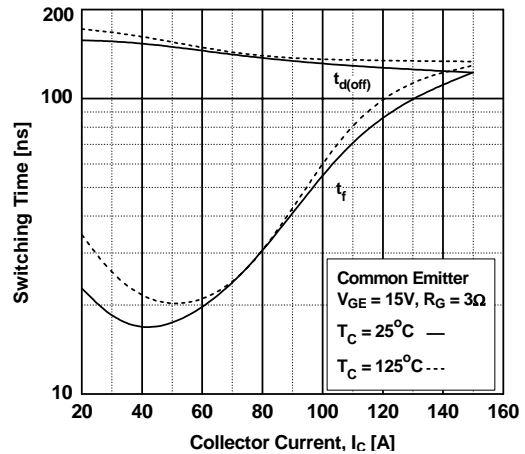


Figure 17. Switching Loss vs. Gate Resistance

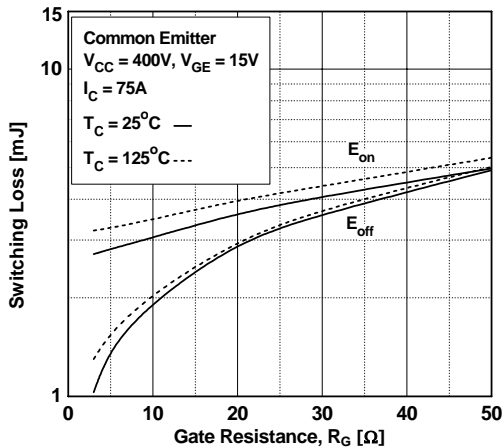
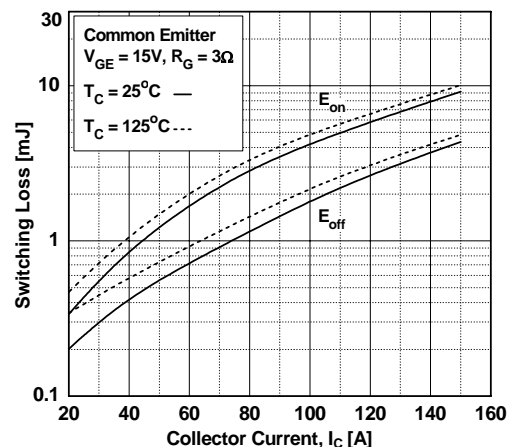


Figure 18. Switching Loss vs. Collector Current



Typical Performance Characteristics

Figure 19. Turn off Switching SOA Characteristics

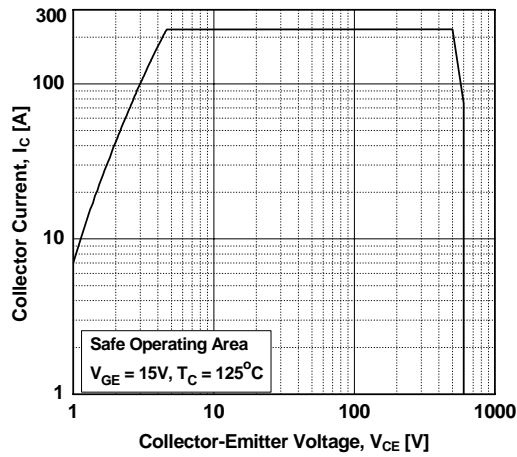
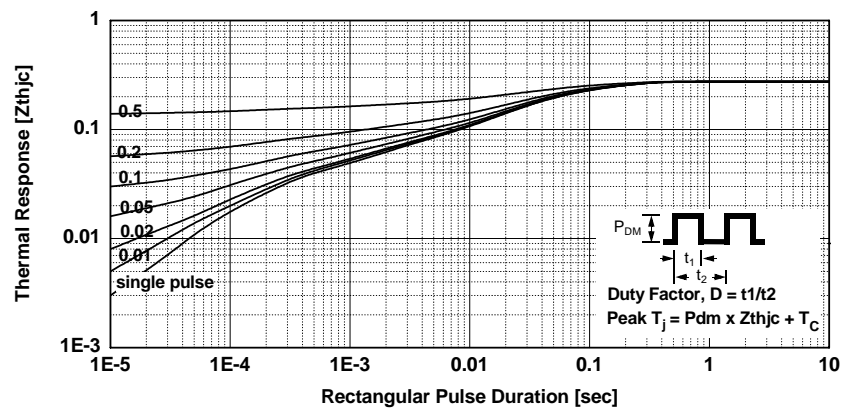
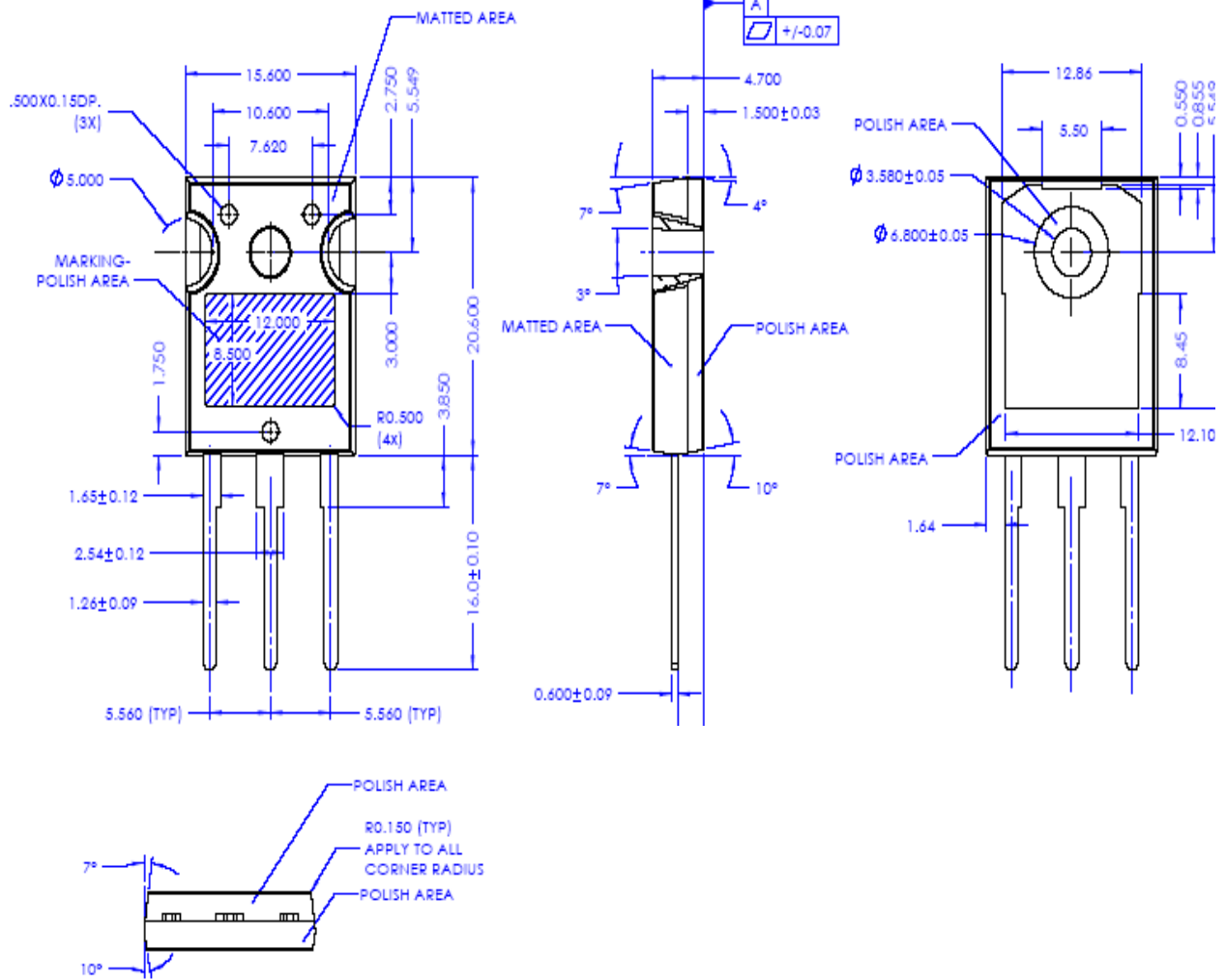


Figure 20. Transient Thermal Impedance of IGBT



Mechanical Dimensions

TO-247AB (FKS PKG CODE 001)



Dimensions in Millimeters



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